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SLPS250A - MAY 2010 - REVISED AUGUST 2011

Dual P-Channel NexFET[™] Power MOSFET

Check for Samples: CSD75211W1723

FEATURES

- Dual P-Ch MOSFETs
- Common Source Configuration
- Small Footprint 1.7 mm × 2.3 mm
- Ultra Low Q_g and Q_{gd}
- Pb Free
- RoHS Compliant
- Halogen Free

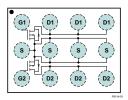
APPLICATIONS

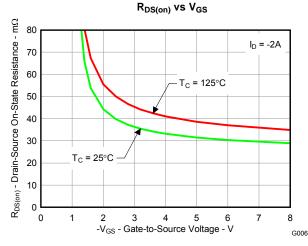
- Battery Management
- Battery Protection
- DC-DC Converters

DESCRIPTION

The device has been designed to deliver the lowest on resistance and gate charge in the smallest outline possible with thermal characteristics in an ultra low profile. Low on resistance and gate charge coupled with the small footprint and low profile make the device ideal for battery operated space constrained application in load management as well as DC-DC converter applications

Top View





PRODUCT SUMMARY

V _{DS}	Drain to Source Voltage	-20		V
Qg	Gate Charge Total (-4.5V)	4.5		nC
Q _{gd}	Gate Charge Gate to Drain	0.9		nC
	Drain to Source On Resistance	$V_{GS} = -1.8V$	50	mΩ
R _{DS(on)}		$V_{GS} = -2.5V$	39	mΩ
		$V_{GS} = -4.5V$	32	mΩ
V _{GS(th)}	Threshold Voltage	-0.7		V

ORDERING INFORMATION

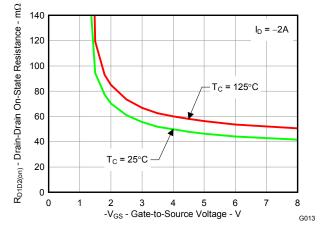
Device	Package	Media	Qty	Ship
CSD75211W1723	1.7-mm × 2.3-mm Wafer Level Package	7-Inch Reel	3000	Tape and Reel

ABSOLUTE MAXIMUM RATINGS

$T_A = 2$	5°C unless otherwise stated	VALUE	UNIT
V_{DS}	Drain to Source Voltage	-20	V
V_{GS}	Gate to Source Voltage	±8	V
	Continuous Drain Current (1) (2)(3)	4.5	
ID	Pulsed Drain Current (1) (2)(3)	-4.5	A
	Continupus Gate Clamp Current (4)	0	А
l _G	Pulsed Gate Clamp Current (4)	-6	
PD	Power Dissipation (1)	1.5	W
T _J , T _{STG}	Operating Junction and Storage Temperature Range	-55 to 150	°C

(1) May be limited by Max source current

- (2) Based on Min Cu footprint
- (3) Per MOSFET
- (4) Total for device



R_{D1D2(on)} vs V_{GS}

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ELECTRICAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Static Cl	haracteristics		·			
BV _{DSS}	Drain to Source Voltage	$V_{GS} = 0V, I_D = -250\mu A$	-20			V
I _{DSS}	Drain to Source Leakage Current	V _{GS} = 0V, V _{DS} = -16V			-1	μA
I _{GSS}	Gate to Source Leakage Current	$V_{DS} = 0V, V_{GS} = \pm 8V$			±100	nA
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$	-0.4	-0.7	-1.1	V
		$V_{GS} = -1.8V, I_{DS} = -2A$		50	70	mΩ
R _{DS(on)}	Drain to Source On Resistance	$V_{GS} = -2.5V, I_{DS} = -2A$		39	50	mΩ
		$V_{GS} = -4.5V, I_{DS} = -2A$		32	40	mΩ
		$V_{GS} = -1.8V, I_{DS} = -2A$		80	110	mΩ
R _{DD(on)}	Drain to Drain On Resistance	$V_{GS} = -2.5V, I_{DS} = -2A$		61	75	mΩ
		$V_{GS} = -4.5V, I_{DS} = -2A$		46	55	mΩ
g _{fs}	Transconductance	V _{DS} = -10V, I _D = -2A		6.4		S
Dynamic	Characteristics					
C _{ISS}	Input Capacitance	V _{GS} = 0V,		460	600	pF
C _{OSS}	Output Capacitance	$V_{DS} = -10V,$		220	290	pF
C _{RSS}	Reverse Transfer Capacitance	f = 1MHz		73	95	pF
R _G	Seried Gate Resistance			1.6	3.2	Ω
Qg	Gate Charge Total (-4.5V)			4.5	5.9	nC
Q _{gd}	Gate Charge Gate to Drain	V 10V L 2A		0.9		nC
Q _{gs}	Gate Charge Gate to Source	V _{DS} = -10V, I _D = -2A		0.9		nC
Q _{g(th)}	Gate Charge at Vth			0.4		nC
Q _{OSS}	Output Charge	$V_{DS} = -17V, V_{GS} = 0V$		4.9		nC
t _{d(on)}	Turn On Delay Time			3.7		ns
t _r	Rise Time	$V_{DS} = -10V, V_{GS} = -4.5V,$		4.1		ns
t _{d(off)}	Turn Off Delay Time	$I_D = -2A, R_G = 2\Omega$		9.1		ns
t _f	Fall Time			1.6		ns
Diode Cl	haracteristics		·			
V_{SD}	Diode Forward Voltage	$I_D = -2A, V_{GS} = 0V$		0.7	1	V
Q _{rr}	Reverse Recovery Charge	V _{DD} = -17V, I _F = -2A,		11		nC
t _{rr}	Reverse Recovery Time	di/dt = 300A/µs		19		ns

THERMAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

PARAMETER		MIN	TYP	MAX	UNIT
R _{θJA}	Thermal Resistance Junction to Ambient (Minimum Cu area) (1) (2)			160	°C/W
R _{θJA}	Thermal Resistance Junction to Ambient (1 in ² Cu area) ^{(2) (3)}			69	°C/W

Device mounted on FR4 material with minimum Cu mounting area. (1)

Measured with both devices biased in a parallel condition. Device mounted on FR4 material with 1 in² of 2oz. Cu.

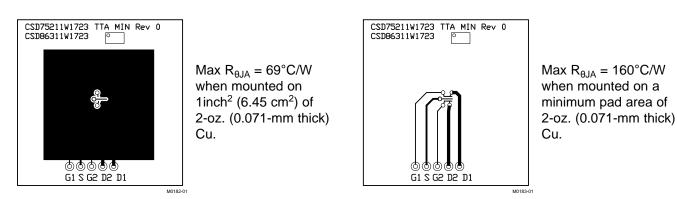
(2) (3)



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TYPICAL MOSFET CHARACTERISTICS

($T_A = 25^{\circ}C$ unless otherwise stated)

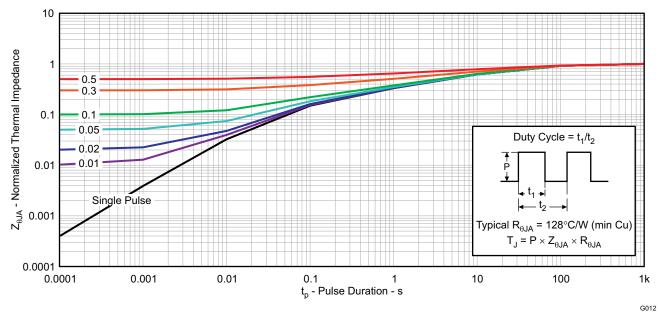


Figure 1. Transient Thermal Impedance

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TYPICAL MOSFET CHARACTERISTICS (continued)

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

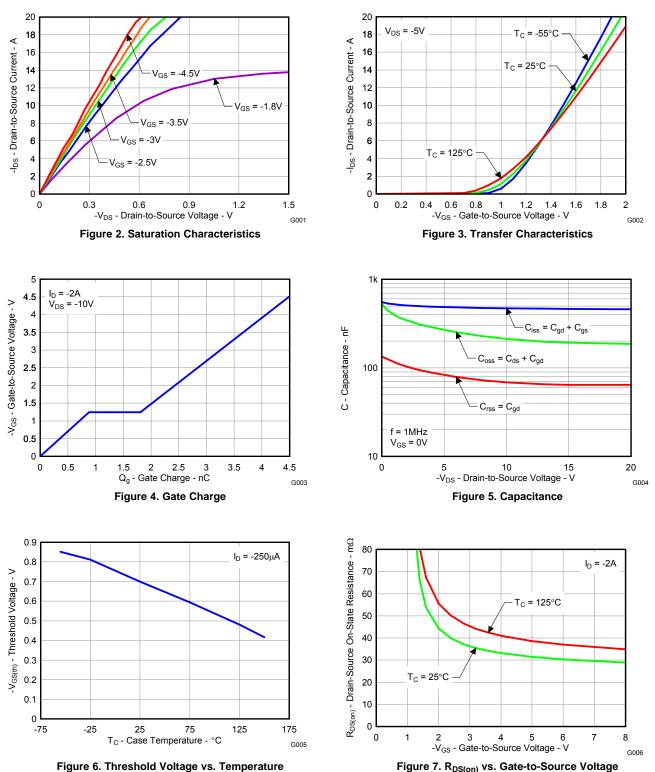


Figure 7. R_{DS(on)} vs. Gate-to-Source Voltage



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TYPICAL MOSFET CHARACTERISTICS (continued)

$(T_A = 25^{\circ}C \text{ unless otherwise stated})$

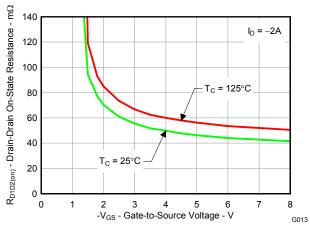


Figure 8. R_{D1D2(on)} vs. Gate-to-Source Voltage

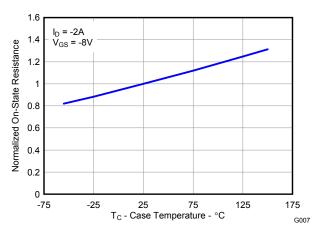
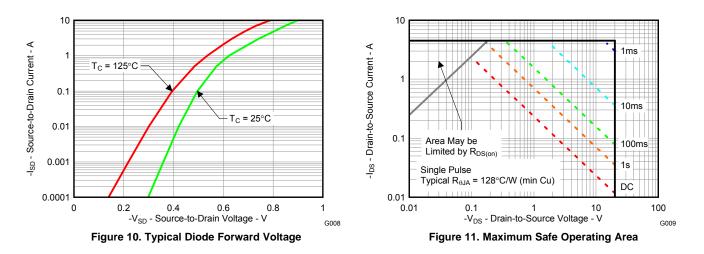
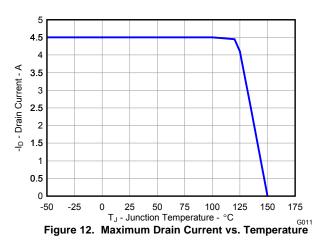


Figure 9. Normalized On-State Resistance vs. Temperature



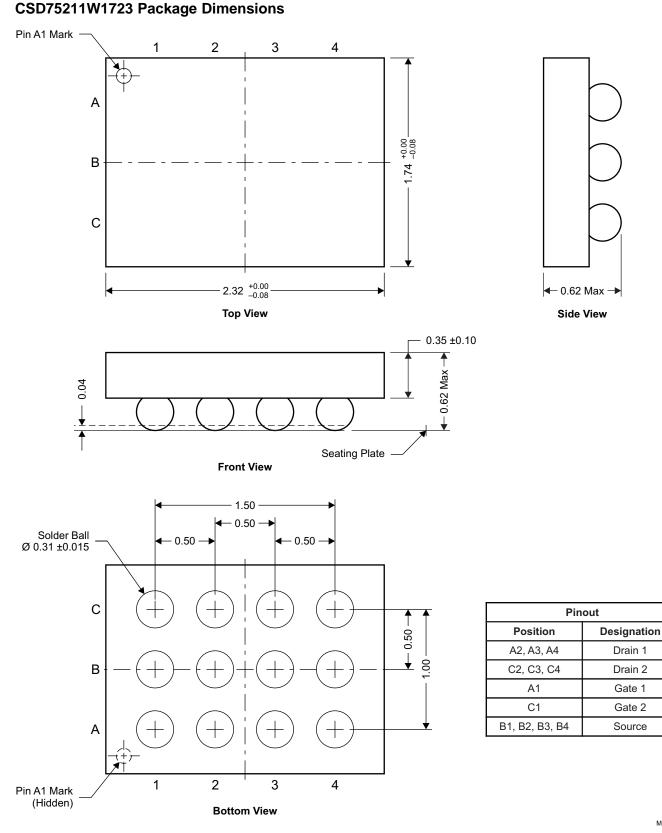


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TEXAS INSTRUMENTS

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MECHANICAL DATA



NOTE: All dimensions are in mm (unless otherwise specified)

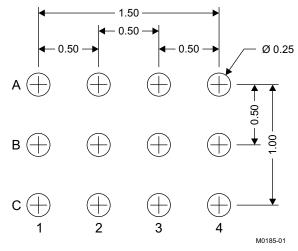


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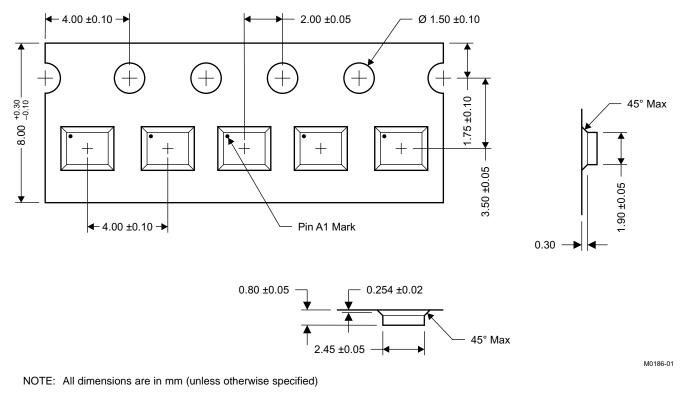
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Land Pattern Recommendation



NOTE: All dimensions are in mm (unless otherwise specified)

Tape and Reel Information



REVISION HISTORY

Cł	nanges from Original (May 2010) to Revision A	Page
•	Changed V_{GS} in the Abs Max Ratings table From: +8 To: ±8	1

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